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## Correction: Structural, electronic, optical, elastic, thermodynamic and thermal transport properties of Cs<sub>2</sub>AgInCl<sub>6</sub> and Cs<sub>2</sub>AgSbCl<sub>6</sub> double perovskite semiconductors using a first-principles study

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Correction for 'Structural, electronic, optical, elastic, thermodynamic and thermal transport properties of Cs<sub>2</sub>AgInCl<sub>6</sub> and Cs<sub>2</sub>AgSbCl<sub>6</sub> double perovskite semiconductors using a first-principles study' by Keqing Zhang et al., *Phys. Chem. Chem. Phys.*, 2023, 25, 31848–31868, <https://doi.org/10.1039/d3cp03795a>.

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